Panasonic

MOS FET FC6B21150L1

FC6B21150L1 Gate resistor installed Dual N-channel MOS FET

For lithium-ion secondary battery protection circuits

Features

- Low source-source ON resistance:Rss(on) typ. = $4.3 \text{ m}\Omega(\text{VGS} = 3.8 \text{ V})$
- CSP(Chip Size Package)
- · RoHS compliant (EU RoHS / MSL:Level 1 compliant)
- Marking Symbol: 16

Packaging

Embossed type (Thermo-compression sealing): 1 000 pcs / reel (standard)

Absolute Maximum Ratir	ngs Ta=25	°C			
Parameter		Symbol	Rating	Unit	
Source-source Voltage		VSS	12	V	
Gate-source Voltage *3		VGS	±10.5	V	
Source Current	DC ^{*1}	IS1	8	А	
	DC *2	IS2	17	Α	
	Pulse *3	ISp	80	А	
Total Power Dissipation	DC ^{*1}	PD1	0.45	W	
	DC *2	PD2	2.1	W	
Channel Temperature		Tch	150	°C	
Storage Temperature Range		Tstg	-55 to +150	°C	
Thermal resistance (ch-a)	DC ^{*1}	Rth1	278	°C/W	
	DC *2	Rth2	59	°C/W	
Note *1 Mounted on ER4 boar					

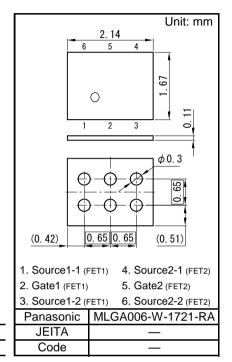
Note *1 Mounted on FR4 board

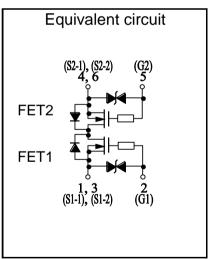
(25.4mm \times 25.4mm \times t1.0mm, 36 μ m Copper)

*2 Mounted on Ceramic substrate

(70 mm \times 70 mm \times t1.0 mm).

*3 t = 10 $\mu s,$ Duty Cycle \leq 1 %







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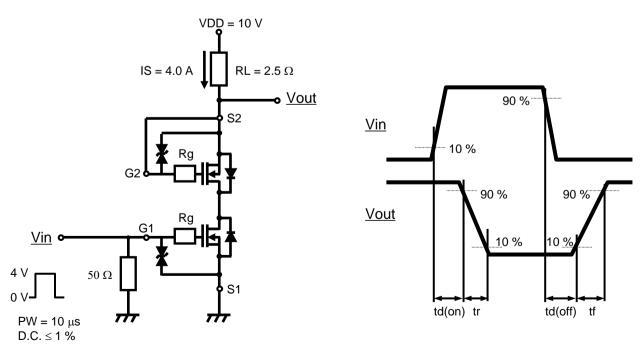
■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	12			V	
Zero Gate Voltage Source Current	ISSS	VSS = 12 V, VGS = 0 V			1.0	μΑ	
Gate-source Leakage Current	IGSS	VGS = ±8 V, VSS = 0 V VGS = ±5 V, VSS = 0 V			±10 ±1.0	μA	
Gate-source Threshold Voltage	Vth	IS = 0.84 mA, VSS = 10 V	0.35	0.90	1.4	V	
Source-source On-state Resistance	RSS(on)1	IS = 4.0 A, VGS = 4.5 V	3	4	5.1		
	RSS(on)2	IS = 4.0 A, VGS = 3.8 V	3.2	4.3	5.5	mΩ	
	RSS(on)3	IS = 4.0 A, VGS = 3.1 V	3.5	4.8	6.8		
	RSS(on)4	IS = 4.0 A, VGS = 2.5 V	3.8	5.9	10		
Body Diode Forward Voltage	VF(s-s)	IF = 4.0 A, VGS = 0 V		0.8	1.2	V	
Input Capacitance ^{*1}	Ciss			2760			
Output Capacitance ^{*1}	Coss	VSS = 10 V, VGS = 0 V, f = 1 MHz		450		pF	
Reverse Transfer Capacitance *1	Crss			390			
Turn-on delay Time *1,*2	td(on)	VDD = 10 V, VGS = 0 to 4.0 V		4.1			
Rise Time ^{*1,*2}	tr	IS = 4.0 A		5.2		μs	
Turn-off delay Time ^{*1,*2}	td(off)	VDD = 10 V, VGS = 4.0 to 0 V		12.9			
Fall Time ^{*1,*2}	tf	IS = 4.0 A		8.3		μs	
Total Gate Charge ¹¹	Qg	VDD = 10 V		26			
Gate-source Charge ^{*1}	Qgs	VGS = 0 to 4.0 V,		9		nC	
Gate-drain Charge ^{*1}	Qgd	IS = 4.0 A		8			

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

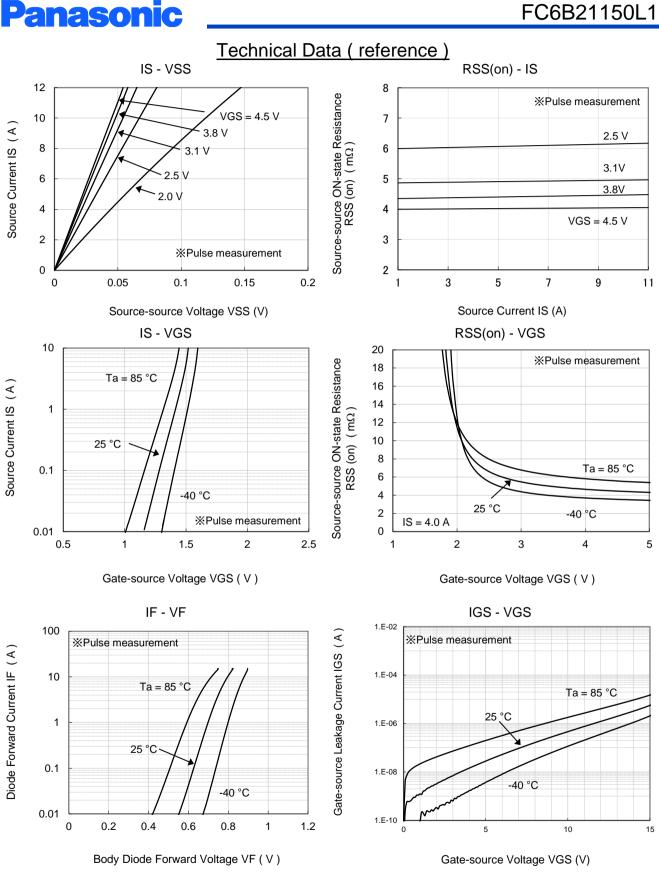
*1 Guaranteed by design, not subject to production testing

*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time



Note2 : Measurement circuit

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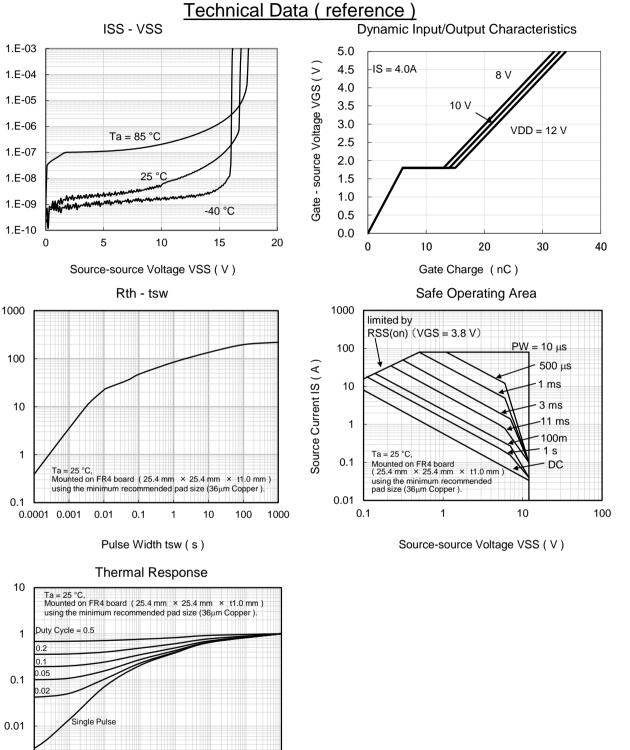
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Zero Gate Voltage Source Current ISS

Thermal Resistance Rth (°C/W)

Normalized Effective Transient Thermal Impedance

0.001



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0.0001 0.001

0.01

0.1

1

Square Wave Pulse Duration (s)

10

100

1000

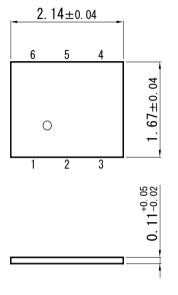
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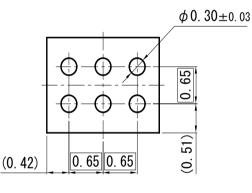


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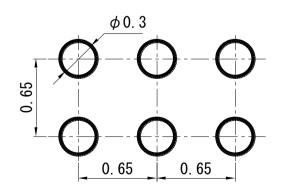
Unit: mm





■ Land Pattern (Reference)

Unit: mm



Established : 2015-10-23 Revised : ###-##-##

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